

RJK03E4DPA

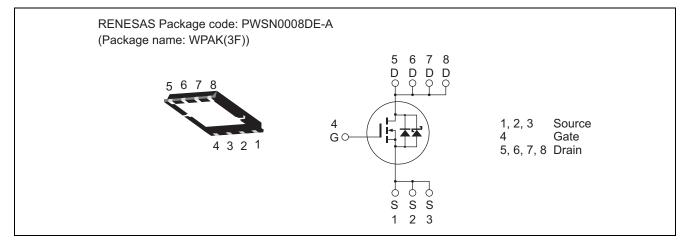
 $30V, 45A, 3.4m\Omega$ max. Built in SBD N Channel Power MOS FET High Speed Power Switching

R07DS0945EJ0400 Rev.4.00 Mar 22, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

Item	Symbol	Ratings	$(Ta = 25^{\circ}C)$ Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±12	V
Drain current	Ι _D	45	А
Drain peak current	I _{D(pulse)} Note1 180		А
Body-drain diode reverse drain current	I _{DR}	45	А
Avalanche current	AP Note 2	17	А
Avalanche energy	E _{AR} Note 2	28.9	mJ
Channel dissipation	Pch Note3	40	W
Channel to case thermal impedance	θch-c ^{Note3}	3.13	°C/W
Channel temperature	Tch	150	٥°
Storage temperature	Tstg	-55 to +150	۵°

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. Tc = 25°C



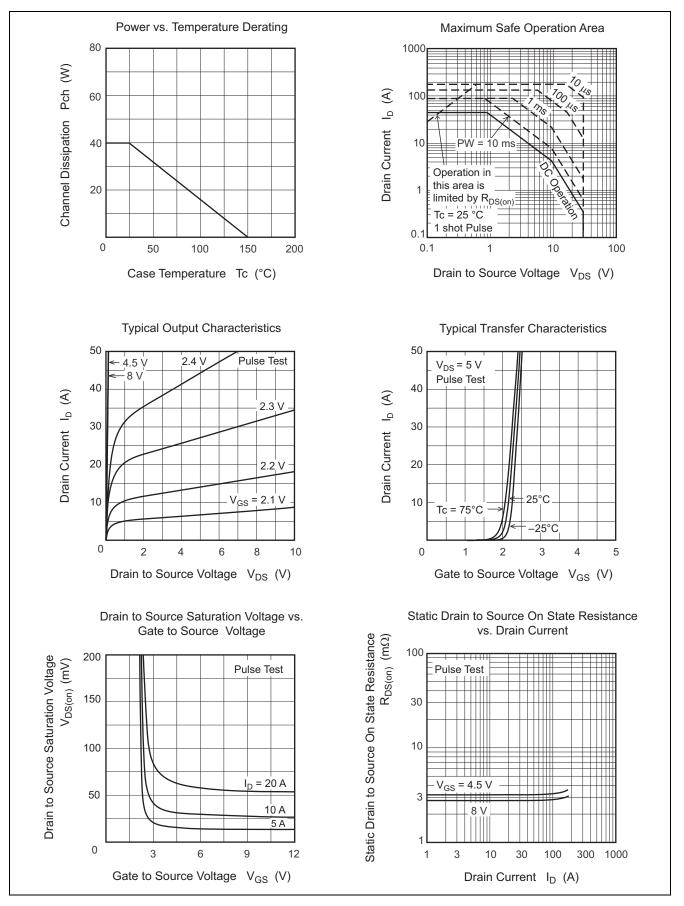
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	—	—	±0.1	μΑ	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1	mA	$V_{DS} = 30 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	2.8	3.4	mΩ	$I_D = 22.5A, V_{GS} = 8.0 V^{Note4}$
resistance	R _{DS(on)}	_	3.2	4.0	mΩ	$I_D = 22.5A, V_{GS} = 4.5 V^{Note4}$
Forward transfer admittance	y _{fs}	_	115	_	S	$I_D = 22.5A, V_{DS} = 5 V^{Note4}$
Input capacitance	Ciss	_	4300	6020	pF	V _{DS} = 10 V
Output capacitance	Coss	_	500	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	330	_	pF	
Gate Resistance	Rg		1.7	3.4	Ω	
Total gate charge	Qg	_	33		nC	V _{DD} = 10 V V _{GS} = 4.5 V I _D = 45 A
Gate to source charge	Qgs		11	_	nC	
Gate to drain charge	Qgd		10		nC	
Turn-on delay time	t _{d(on)}		18		ns	$V_{GS} = 8 V, I_D = 22.5 A$
Rise time	tr		8		ns	$V_{DD} \cong 10 \text{ V}$ $R_{L} = 0.44\Omega$ $Rg = 4.7 \Omega$
Turn-off delay time	t _{d(off)}	_	66	_	ns	
Fall time	t _f		17		ns	
Body–drain diode forward voltage	V _{DF}	_	0.39		V	$I_F = 2 A, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t _{rr}	_	29		ns	I _F =45 A, V _{GS} = 0
time						$di_F/dt = 100 \text{ A}/\mu \text{s}$

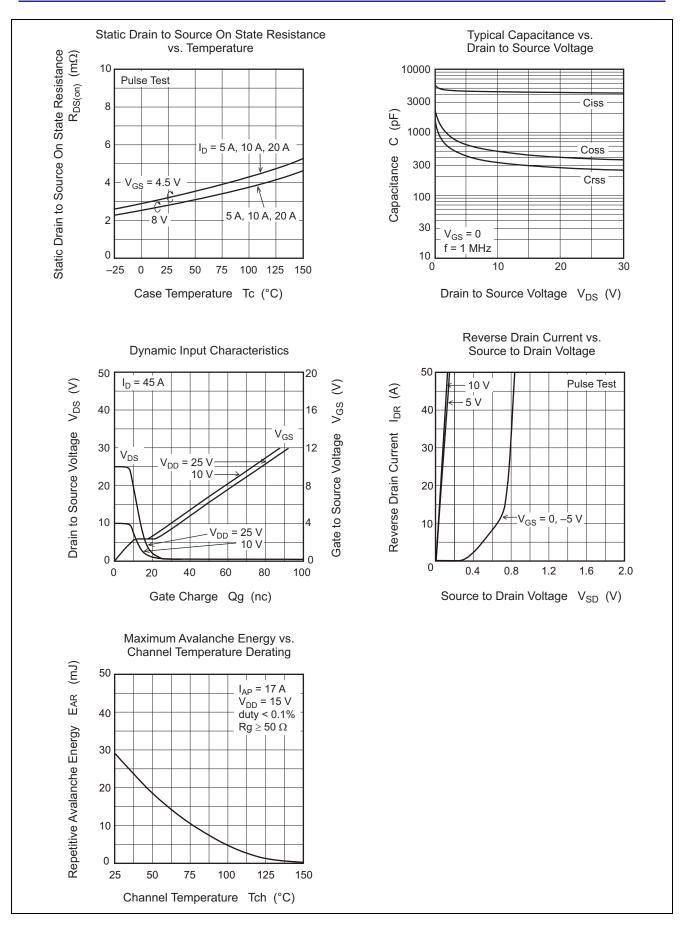
Notes: 4. Pulse test

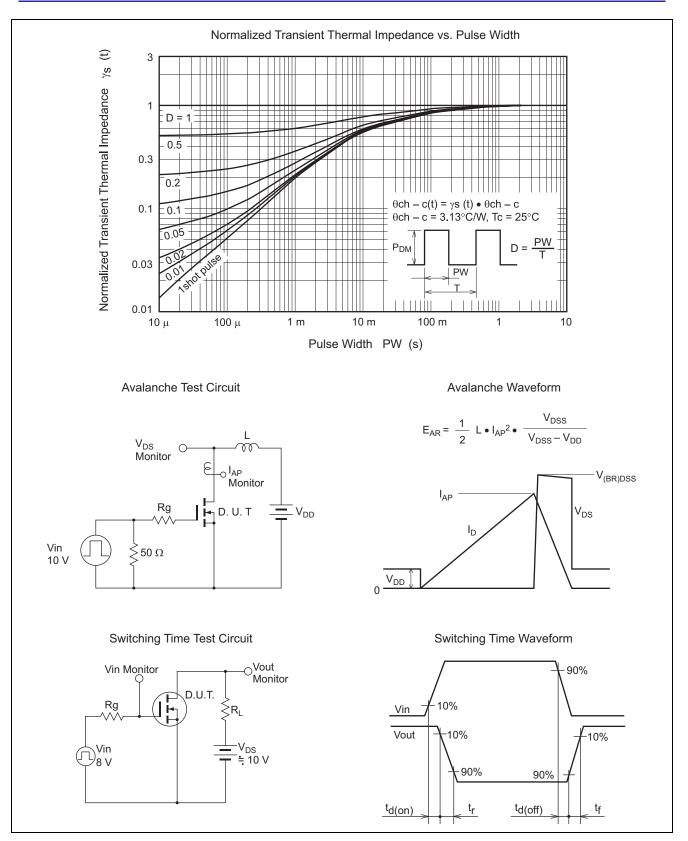


Main Characteristics

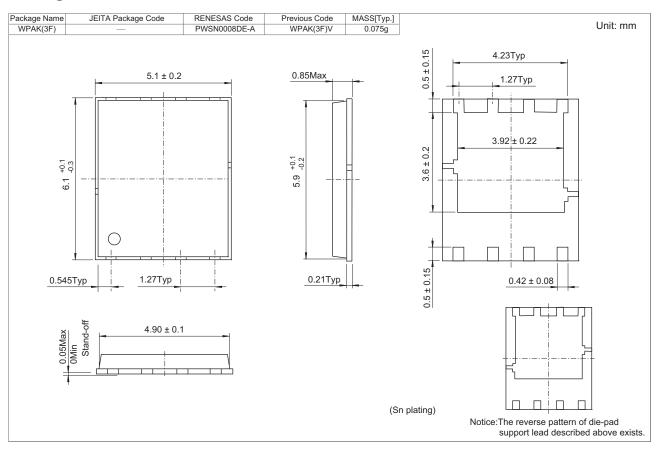








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK03E4DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".



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